

# **Excellent Integrated System Limited**

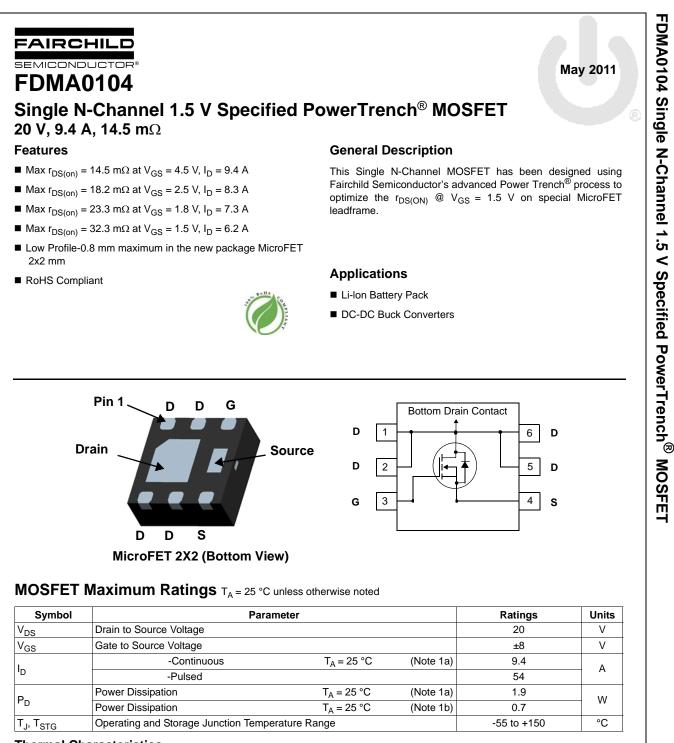
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Fairchild Semiconductor FDMA0104

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>





## **Thermal Characteristics**

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	65	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	180	0/11

### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
104	FDMA0104	MicroFET 2X2	7 "	12 mm	3000 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	20			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		15		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 16 V, V <sub>GS</sub> = 0 V			1	μΑ	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250 μA	0.4	0.6	1.0	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-3		mV/°C	
	Static Drain to Source On Resistance	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 9.4 A		11.3	14.5		
		V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 8.3 A		12.7	18.2	mΩ	
r <sub>DS(on)</sub>		V <sub>GS</sub> = 1.8 V, I <sub>D</sub> = 7.3 A		15.0	23.3		
		$V_{GS} = 1.5 \text{ V}, I_D = 6.2 \text{ A}$		18.3	32.3		
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 9.4 A, T <sub>J</sub> = 125 °C		14.7	18.3	1	
9 <sub>FS</sub>	Forward Transconductance	V <sub>DD</sub> = 5 V, I <sub>D</sub> = 9.4 A		56		S	
Dvnamic	Characteristics						
C <sub>iss</sub>	Input Capacitance			1260	1680	pF	
C <sub>oss</sub>	Output Capacitance	$V_{\rm DS} = 10 \text{ V}, \text{ V}_{\rm GS} = 0 \text{ V},$		180	240	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1 MHz		122	185	pF	
R <sub>g</sub>	Gate Resistance			1.9		Ω	
•	Characteristics				1		
t <sub>d(on)</sub>	Turn-On Delay Time			9	17	ns	
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 10 V, I <sub>D</sub> = 9.4 A,		6	11	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		37	58	ns	
t <sub>f</sub>	Fall Time			6	11	ns	
Qg	Total Gate Charge	$V_{GS} = 0 V$ to 4.5 V		17.5		nC	
	Total Gate Charge	$V_{GS} = 0 V \text{ to } 2.5 V$		10.0		nC	
	Total Gate Charge	$V_{GS} = 0 \text{ V to } 1.8 \text{ V} \text{ V}_{DD} = 10 \text{ V},$		7.4		nC	
	Total Gate Charge	$V_{GS} = 0 \text{ V to } 1.5 \text{ V}$ I <sub>D</sub> = 9.4 A		6.2		nC	
Q <sub>gs</sub>	Gate to Source Charge			1.7		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			2.7		nC	

# Diode Characteristi

I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current			2.0	А
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.0 A$ (Note 2)	0.63	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 9.4 A, di/dt = 100 A/μs	16	29	ns
Q <sub>rr</sub>	Reverse Recovery Charge	$I_F = 9.4 \text{ A, di/dl} = 100 \text{ A/}\mu\text{s}$ 5 1		10	nC

FDMA0104 Single N-Channel 1.5 V Specified PowerTrench<sup>®</sup> MOSFET



NOTES:

1. R<sub>0JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.

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2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0%.

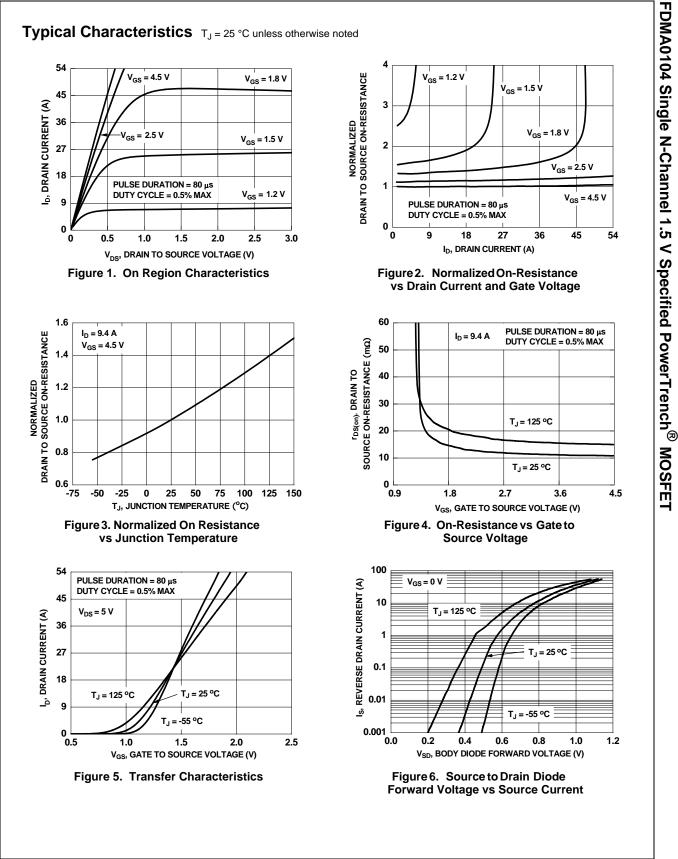


a.65 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

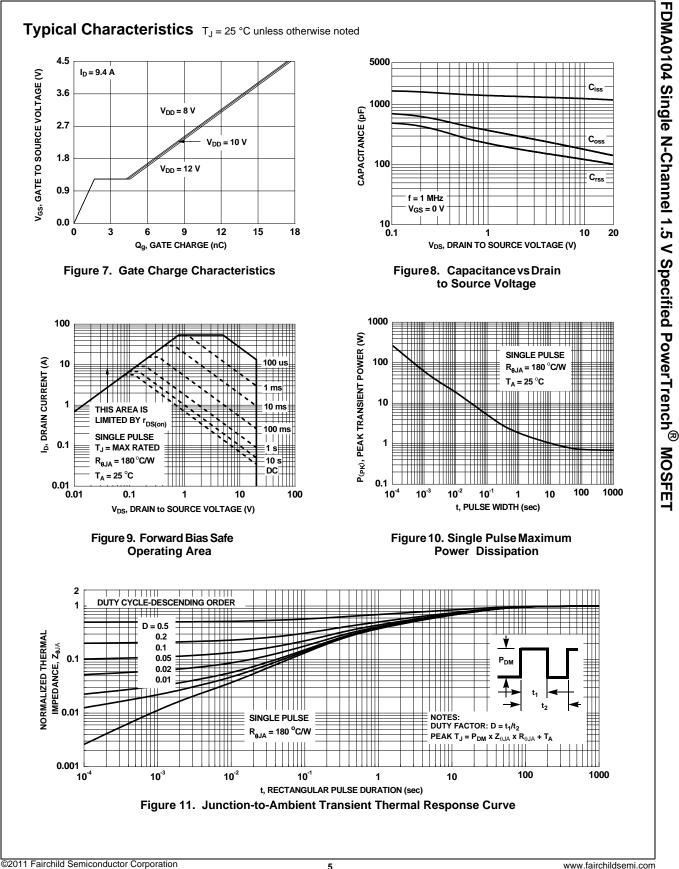
b. 180 °C/W when mounted on a minimum pad of 2 oz copper.

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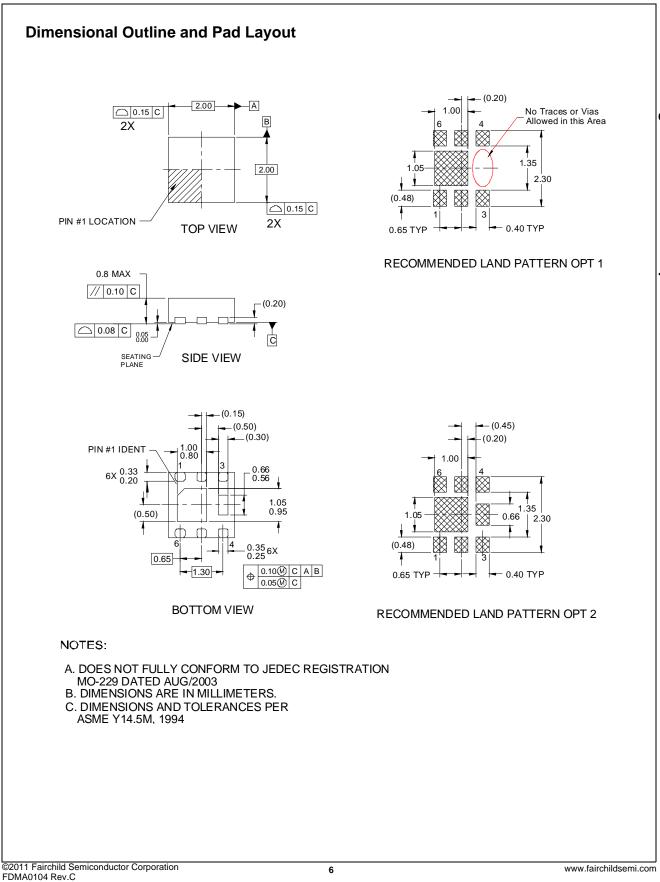






FDMA0104 Rev.C









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#### PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
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